NSN 5962-01-172-2379

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Yes - demil/mli



View Online at https://aerobasegroup.com/nsn/5962-01-172-2379

Body Length:	
0.960 inches	
Body Width:	
Between 0.220 inche	es and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Di	issipation Rating:
715.0 milliwatts	
Operating Tempura	iture Range:
-55.0/+125.0 degree	s celsius
Storage Tempuratu	ire Range:
-65.0/+150.0 degree	s celsius
Features Provided:	
Hermetically sealed	and burn in and programmable and schottky and 3-state output and w/active pull-up
Inclosure Material:	
Ceramic	
Inclosure Configura	ation:
Dual-in-line	
Output Logic Form	:
Transistor-transistor	logic
Input Circuit Patter	n:
12 input	
Case Outline Sourc	e And Designator:
D-6 mil-m-38510	
Terminal Surface T	reatment:
Solder	
Voltage Rating And	I Type Per Characteristic:
5.5 volts power sour	rce
Time Rating Per Ch	acteristic:
125.00 nanoseconds	s propagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Typ	be:
Rom	
Test Data Documer	nt:
96906-mil-std-883 st	andard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	Quantity:
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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